

# 42-DL214

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**Optical Fiber Transmitting IC**

Preiminary



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## 42-DL214

# OPTICAL FIBER TRANSMITTING IC

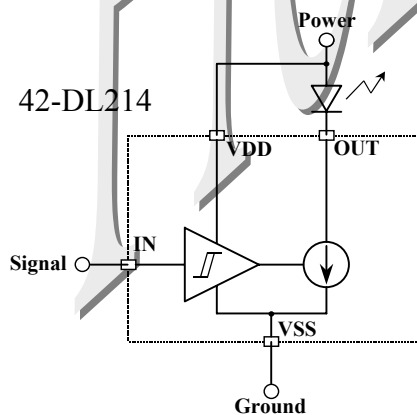
### GENERAL DESCRIPTION

42-DL214 is a driver IC designed for the application of high-speed optical fiber transmission. It integrates the LED driver with constant current output to reduce the complexity and the cost of the transmission module. 42-DL214 can transmit with the speed up to 25Mb/s. 42-DL214 are fabricated by using CMOS technology with low power consumption purpose.

### FEATURES

1. TTL interface compatible
2. High speed (up to 25Mb/s)
3. Uniform output waveform
4. Constant current output
5. Low power consumption
6. Wide range for Supply Voltage (2.2V-3.6V)

### BLOCK DIAGRAM And APPLICATION CIRCUIT





**ABSOLUTE MAXIMUM RATINGS**

Item	Symbol	Rating	Unit
Supply Voltage	$V_{DD}$	-0.5 to +6.5	V
Input Voltage	$V_{IN}$	-0.5 to $V_{DD} + 0.5$	V
Operating Temperature	$T_{opr}$	-40 to +85	°C
Storage Temperature	$T_{stg}$	-55 to +100	°C
Electrostatic Damage	ESD	HBM class 3	
Output Voltage	$V_{OUT}$	-0.5 to $V_{DD} + 0.5$	V

**RECOMMENDED OPERATING CONDITIONS**

ITEM	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	$V_{DD}$	2.2	-	3.6	V
High Level Input Voltage	$V_{IH}$	2.0	-	$V_{DD}$	V
Low Level Input Voltage	$V_{IL}$	0	-	0.8	V

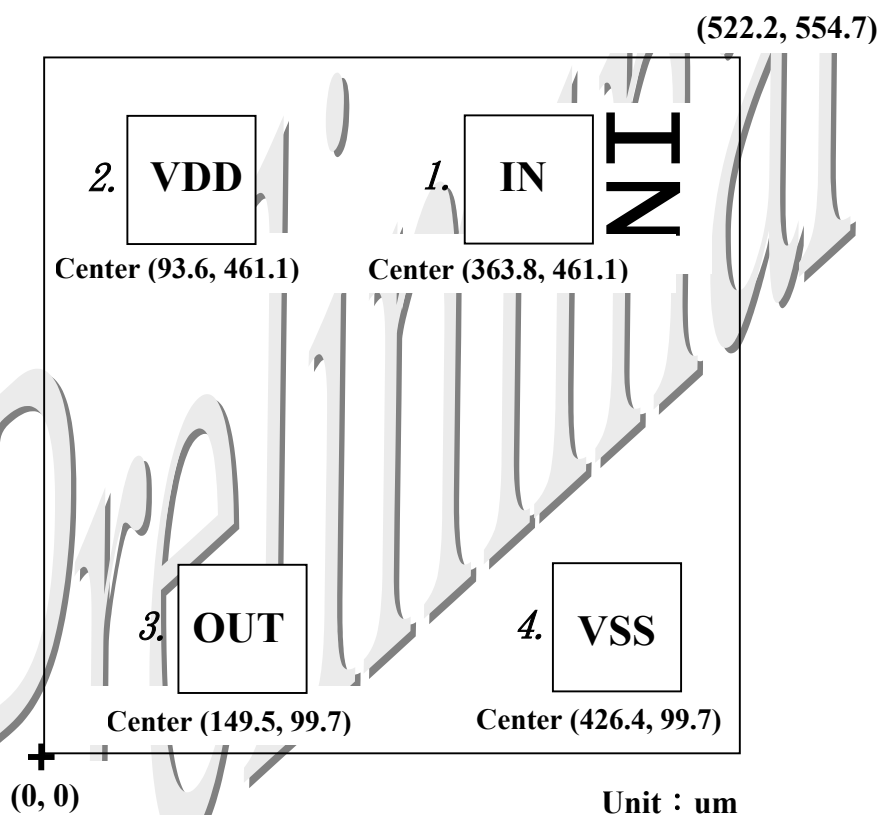
**ELECTRICAL CHARACTERISTICS ( $V_{DD}=2.4V$ ,  $T_A=25^{\circ}C$ , if not mentioned )**

ITEM	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT
High Level Input Voltage	$V_{IH}$	-	2.0	-	$V_{DD}$	V
Low Level Input Voltage	$V_{IL}$	-	0	-	0.8	V
Input Leakage Current	$I_{IN}$	$V_{IN}=V_{DD}$ or $V_{SS}$	-	-	1	uA
Quiescent Supply Current	$I_{DDQ}$	$V_{IN}=V_{DD}$	-	0.5	1.4	mA
Output Sinking Current	$I_{OUT\_ON}$	$V_{IN}=V_{DD}$ $C_{LED}=15pF$ , $V_{FLED}=1.6V$	3.52	4.4	5.28	mA
Output Leakage Current	$I_{OUT\_OFF}$	$V_{OUT}=V_{DD}$ , $V_{IN}=V_{SS}$	-	-	5	uA
Propagation Delay	$T_{PLH}$ , $T_{PHL}$	$C_{LED}=15pF$ , $V_{FLED}=1.6V$	-	-	100	ns
Rise Time, Fall Time of $I_{OUT}$	$T_r$ , $T_f$	$C_{LED}=15pF$ , $V_{FLED}=1.6V$	-	14	-	ns
Pulse Width Distortion	$\Delta tw$	$C_{LED}=15pF$ , $V_{FLED}=1.6V$	- 25	0	25	ns
Jitter of Output Current	$\Delta tj$	$C_{LED}=15pF$ , $V_{FLED}=1.6V$		1	25	ns
Data Rate	$F_{DATA}$	NRZ Code, $C_{LED}=15pF$ , $V_{FLED}=1.6V$	-	-	25	Mb/s

### PAD DESCRIPTIONS

PAD NO.	PAD NAME	DESCRIPTIONS
1	IN	Input Pad(Active High )
2	VDD	Supply Voltage
3	OUT	Output Pad Sinking Current(Active Low)
4	VSS	Ground

### DIE CONFIGURATION



Die Size: 522.2um \* 554.7um  
Die Thickness: 12mil(=300um)  
Pad Size: 100um \* 100um

\* **Note:** SiTI reserves the right to improve the device geometry and manufacturing processes without prior notice. Though these improvements may result in slight geometry changes, they will not affect die electrical characteristics and pad layouts.



## REQUIREMENTS FOR WAFER DELIVERY

- Material : Silicon with P-Substrate
- Diameter : 6 inches( $\approx$ 15cm)
- Thickness : 12 mils( $\approx$ 300um)
- Malfunctioned die : Marked with red ink or equivalent marking

## HANDLING RECOMMENDATION FOR STATIC ELECTRICITY PROTECTION

- (1) Avoid any circumstance that produce static electricity, e.g. rubbing against plastic, during moving, storing and processing 42-DL214.
- (2) Process 42-DL214 in a clean room with proper temperature and humidity.
- (3) Ground all working machines and workers wear anti-electrostatic ring to ground during processing.
- (4) Avoid contact 42-DL214 with bare hands. If unavioded, wear anti-electrostatic ring and use anti-electrostatic tool to pick it up.

## GUARANTED TEMPERATURE AND RETENTION CYCLE

- (1) The device/wafer 42-DL214 should be stored in the nitrogenous chest. The conditions suggested are as follows:
  - Temperature =  $23 \pm 3^{\circ}\text{C}$
  - Relative Humidity =  $50 \pm 10\%$
  - Minimum nitrogen inflow = 3 liters/minute
- (2) If the device/wafer, 42-DL214 is incidentally exposed to the air, use it for manufacturing as soon as possible.
- (3) Under the storage environment specified in item (1), six-month safe storage period is guaranteed.



The products listed herein are designed for ordinary electronic applications, such as electrical appliances, audio-visual equipment, communications devices and so on. Hence, it is advisable that the devices should not be used in medical instruments, surgical implants, aerospace machinery, nuclear power control systems, disaster/crime-prevention equipment and the like. Misusing those products may directly or indirectly endanger human life, or cause injury and property loss.

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Preliminary